

## GEMOLOGICAL INSTITUTE

## **ELECTRONIC COPY**

#### LABORATORY GROWN DIAMOND REPORT

April 18, 2023	
IGI Report Number	LG577394479
Description	LABORATORY GROWN DIAMOND
Shape and Cutting Style	OVAL BRILLIANT
Measurements	12.71 X 8.92 X 5.56 MM
GRADING RESULTS	
Carat Weight	4.01 CARATS
Color Grade	D
Clarity Grade	V\$ 2
Cut Grade	EXCELLENT
ADDITIONAL GRADING INFORMA	ATION
Polish	EXCELLENT
Symmetry	EXCELLENT
Fluorescence	NONE
Inscription(s)	1631 LG577394479

Comments: This Laboratory Grown Diamond was created by Chemical Vapor Deposition (CVD) growth process and may include post-growth treatment. Type IIa

#### LABORATORY GROWN DIAMOND REPORT

### LG577394479 Report verification at igi.org

59%

Pointed

\_\_\_\_

62.3%

PROPORTIONS

Medium To

Thick (Faceted)

13.5%

44%

**CLARITY CHARACTERISTICS** 

**KEY TO SYMBOLS** 

Red symbols indicate internal characteristics.

Green symbols indicate external characteristics.

 $\checkmark$ 7

#### LABORATORY GROWN DIAMOND REPORT

#### GRADING SCALES

#### CLARITY

IF	VVS <sup>1-2</sup>	VS <sup>1-2</sup>	SI <sup>1-2</sup>	l <sup>1-3</sup>
Internally Flawless	Very Very Slightly Included	Very Slightly Included	Slightly Included	Included

## COLOR

D	Е	F	G	Н	Т	J	Faint	Very Light	Light

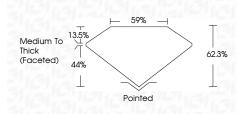


Sample Image Used

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10,2020	
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Polish	EXCELLENT
Symmetry	EXCELLENT
Fluorescence	NONE
Inscription(s)	(G) LG577394479
Comments: This Laboratory created by Chemical Vapo process and may include po Type IIa	or Deposition (CVD) growth



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	I CARATS D	VS 2	ACELLENI 62.3%	869%	Facefed)	Pointed	XCELLENT	577394479

MBN LG6773	n Diamond wo I Vapor Depos s and may Inc #	
Inscription(s)	Comments: Exaction Crown Diamond we created by Chemical Vycor Depose (C/f0) growth process and may inc participating ind	